

Test data, continued

On the plots below the measured *Channel Power* value in the “*Total Channel Power*” column must be -19 dBm and lower.



Figure 8.3-95: Conducted emission at the lower band edge

Frequency: 2110 MHz Mode: Single-carrier operation
 Meas. BW: 1% of EBW Tech.: LTE 5 MHz with IB (IoT1)
 Limit: -19 dBm/50 kHz Notes: None



Figure 8.3-96: Conducted emission 1 MHz away from the lower band edge

Frequency: 2109 MHz Mode: Single-carrier operation
 Meas. BW: 1 MHz Tech.: LTE 5 MHz with IB (IoT1)
 Limit: -19 dBm/MHz Notes: None

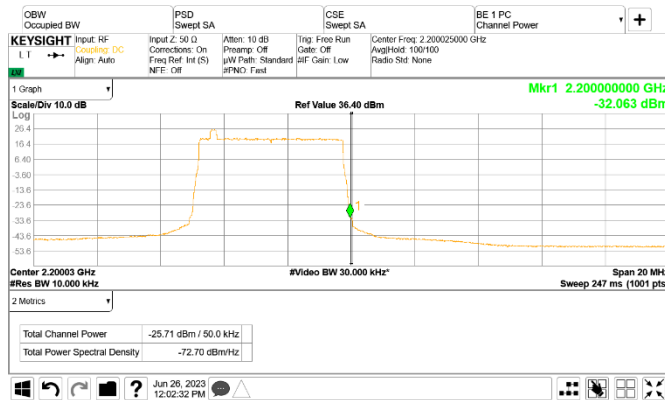


Figure 8.3-97: Conducted emission at the upper band edge

Frequency: 2200 MHz Mode: Single-carrier operation
 Meas. BW: 1% of EBW Tech.: LTE 5 MHz with IB (IoT1)
 Limit: -19 dBm/50 kHz Notes: None

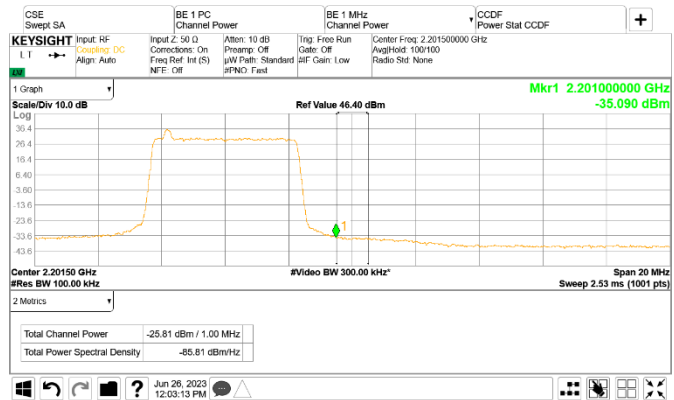


Figure 8.3-98: Conducted emission 1 MHz away from the upper band edge

Frequency: 2201 MHz Mode: Single-carrier operation
 Meas. BW: 1 MHz Tech.: LTE 5 MHz with IB (IoT1)
 Limit: -19 dBm/MHz Notes: None

Test data, continued

On the plots below the measured *Channel Power* value in the “*Total Channel Power*” column must be **-19 dBm** and lower.



Figure 8.3-99: Conducted emission at the lower band edge

Frequency: 2110 MHz Mode: Single-carrier operation
 Meas. BW: 1% of EBW Tech.: LTE 5 MHz with IB (IoT2)
 Limit: -19 dBm/50 kHz Notes: None

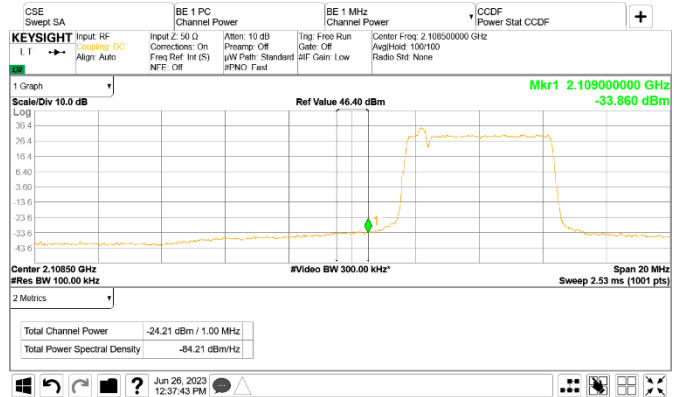


Figure 8.3-100: Conducted emission 1 MHz away from the lower band edge

Frequency: 2109 MHz Mode: Single-carrier operation
 Meas. BW: 1 MHz Tech.: LTE 5 MHz with IB (IoT2)
 Limit: -19 dBm/MHz Notes: None

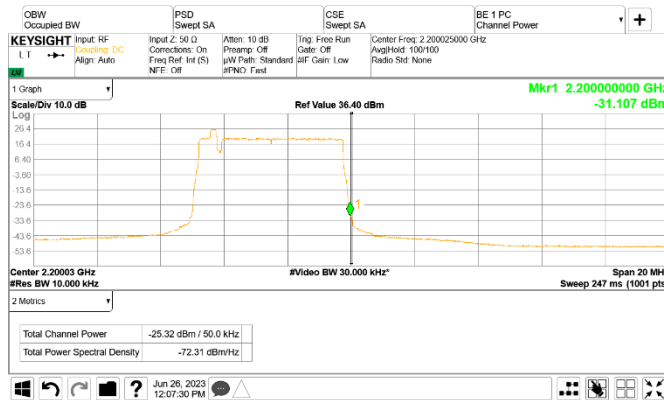


Figure 8.3-101: Conducted emission at the upper band edge

Frequency: 2200 MHz Mode: Single-carrier operation
 Meas. BW: 1% of EBW Tech.: LTE 5 MHz with IB (IoT2)
 Limit: -19 dBm/50 kHz Notes: None

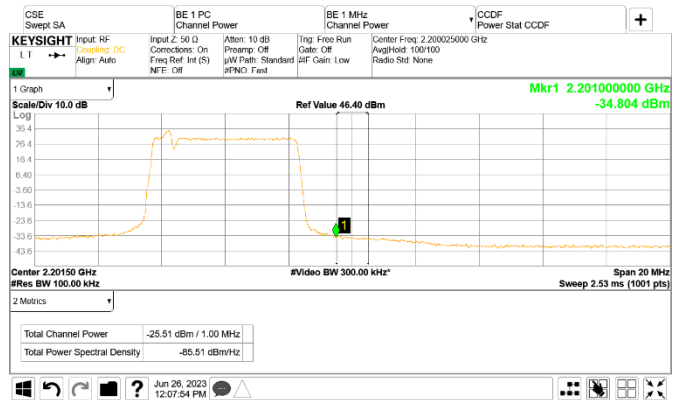


Figure 8.3-102: Conducted emission 1 MHz away from the upper band edge

Frequency: 2201 MHz Mode: Single-carrier operation
 Meas. BW: 1 MHz Tech.: LTE 5 MHz with IB (IoT2)
 Limit: -19 dBm/MHz Notes: None

Test data, continued

On the plots below the measured *Channel Power* value in the “*Total Channel Power*” column must be -19 dBm and lower.

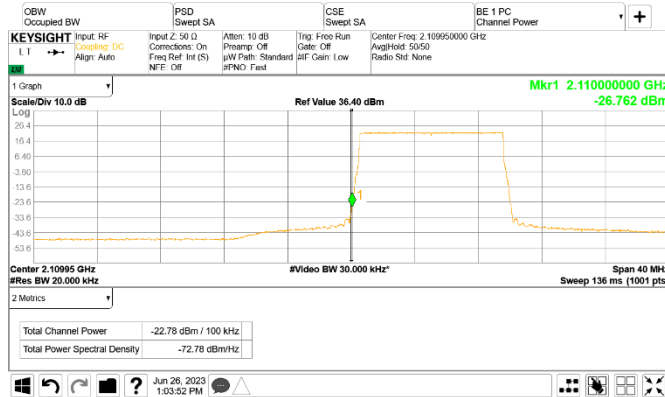


Figure 8.3-103: Conducted emission at the lower band edge

Frequency: 2110 MHz Mode: Single-carrier operation
 Meas. BW: 1% of EBW Tech.: LTE 10 MHz
 Limit: -19 dBm/100 kHz Notes: None



Figure 8.3-104: Conducted emission 1 MHz away from the lower band edge

Frequency: 2109 MHz Mode: Single-carrier operation
 Meas. BW: 1 MHz Tech.: LTE 10 MHz
 Limit: -19 dBm/MHz Notes: None

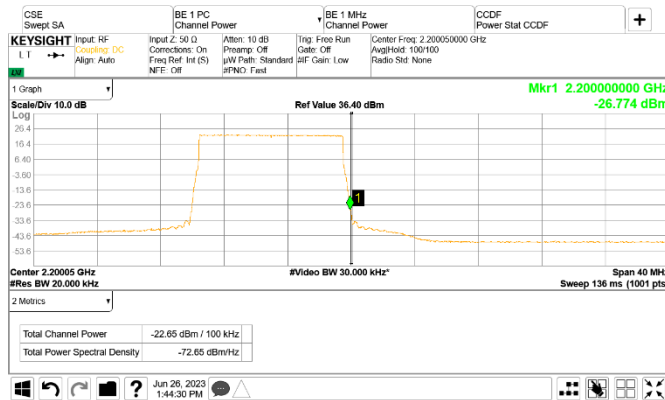


Figure 8.3-105: Conducted emission at the upper band edge

Frequency: 2200 MHz Mode: Single-carrier operation
 Meas. BW: 1% of EBW Tech.: LTE 10 MHz
 Limit: -19 dBm/100 kHz Notes: None

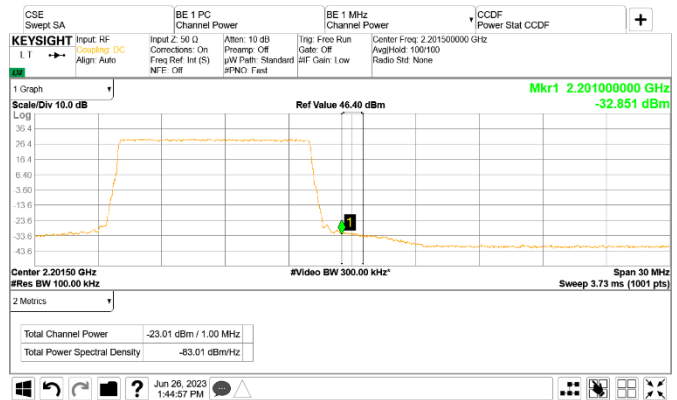


Figure 8.3-106: Conducted emission 1 MHz away from the upper band edge

Frequency: 2201 MHz Mode: Single-carrier operation
 Meas. BW: 1 MHz Tech.: LTE 10 MHz
 Limit: -19 dBm/MHz Notes: None

Test data, continued

On the plots below the measured *Channel Power* value in the “*Total Channel Power*” column must be **-19 dBm** and lower.

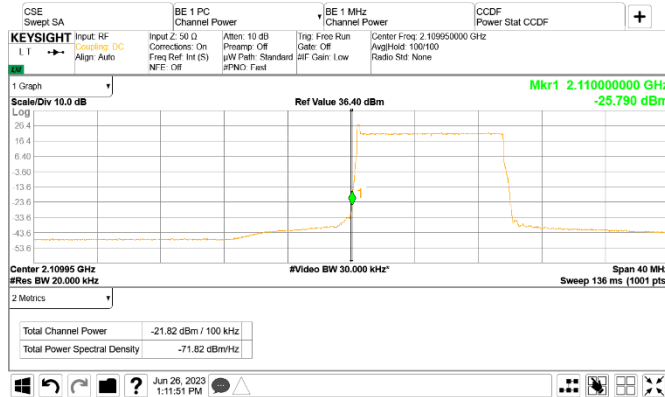


Figure 8.3-107: Conducted emission at the lower band edge

Frequency: 2110 MHz Mode: Single-carrier operation
 Meas. BW: 1% of EBW Tech.: LTE 10 MHz with IoT
 Limit: -19 dBm/100 kHz Notes: None

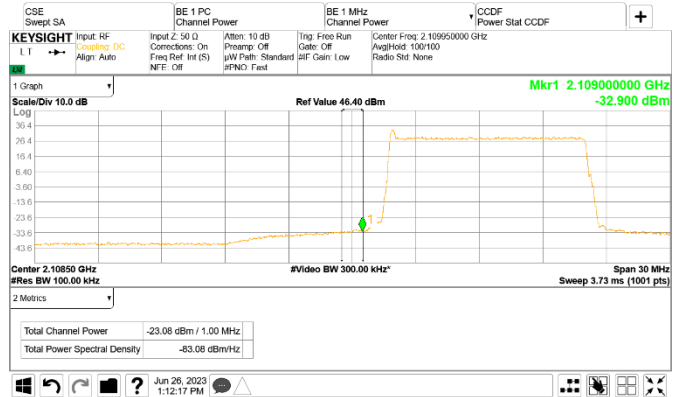


Figure 8.3-108: Conducted emission 1 MHz away from the lower band edge

Frequency: 2109 MHz Mode: Single-carrier operation
 Meas. BW: 1 MHz Tech.: LTE 10 MHz with IoT
 Limit: -19 dBm/MHz Notes: None



Figure 8.3-109: Conducted emission at the upper band edge

Frequency: 2200 MHz Mode: Single-carrier operation
 Meas. BW: 1% of EBW Tech.: LTE 10 MHz with IoT
 Limit: -19 dBm/100 kHz Notes: None

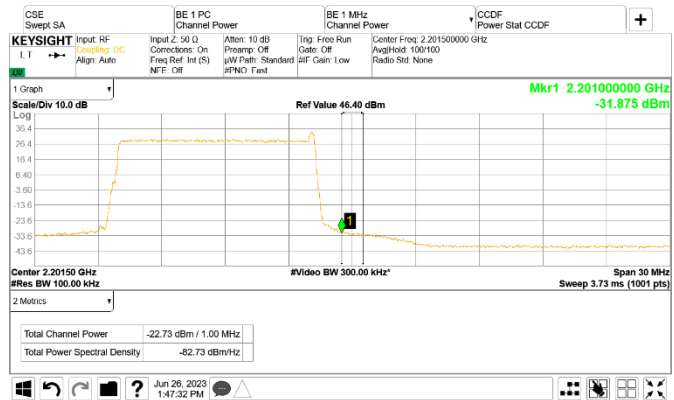


Figure 8.3-110: Conducted emission 1 MHz away from the upper band edge

Frequency: 2201 MHz Mode: Single-carrier operation
 Meas. BW: 1 MHz Tech.: LTE 10 MHz with IoT
 Limit: -19 dBm/MHz Notes: None

Test data, continued

On the plots below the measured *Channel Power* value in the “*Total Channel Power*” column must be -19 dBm and lower.

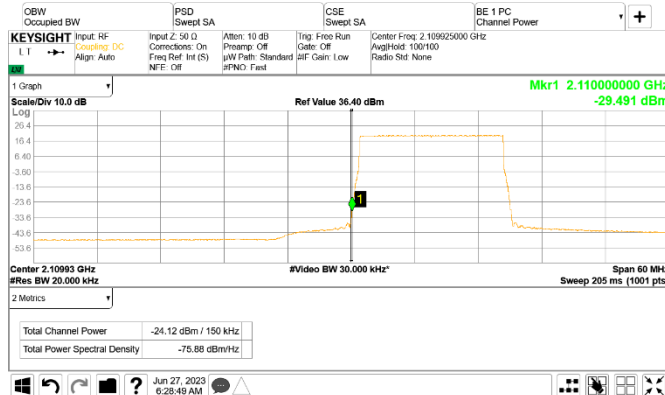


Figure 8.3-111: Conducted emission at the lower band edge

Frequency: 2110 MHz Mode: Single-carrier operation
 Meas. BW: 1% of EBW Tech.: LTE 15 MHz
 Limit: -19 dBm/150 kHz Notes: None

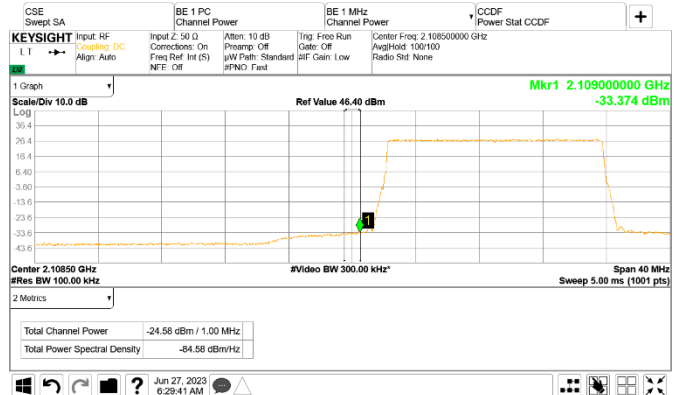


Figure 8.3-112: Conducted emission 1 MHz away from the lower band edge

Frequency: 2109 MHz Mode: Single-carrier operation
 Meas. BW: 1 MHz Tech.: LTE 15 MHz
 Limit: -19 dBm/MHz Notes: None

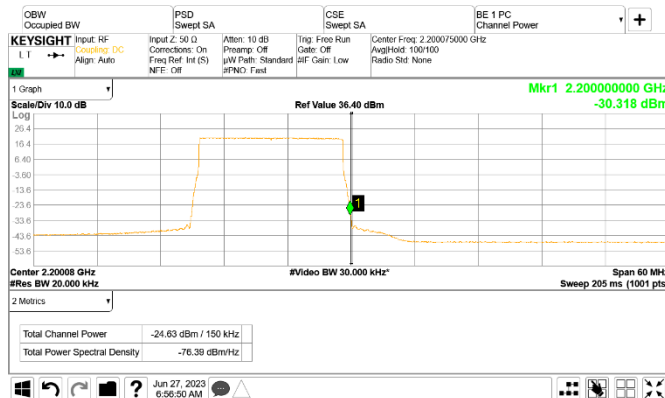


Figure 8.3-113: Conducted emission at the upper band edge

Frequency: 2200 MHz Mode: Single-carrier operation
 Meas. BW: 1% of EBW Tech.: LTE 15 MHz
 Limit: -19 dBm/150 kHz Notes: None

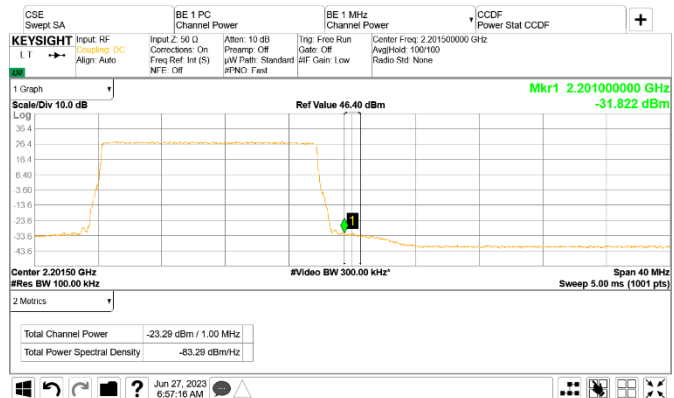


Figure 8.3-114: Conducted emission 1 MHz away from the upper band edge

Frequency: 2201 MHz Mode: Single-carrier operation
 Meas. BW: 1 MHz Tech.: LTE 15 MHz
 Limit: -19 dBm/MHz Notes: None

Test data, continued

On the plots below the measured *Channel Power* value in the “*Total Channel Power*” column must be **-19 dBm** and lower.



Figure 8.3-115: Conducted emission at the lower band edge

Frequency: 2110 MHz Mode: Single-carrier operation
 Meas. BW: 1% of EBW Tech.: LTE 15 MHz with IoT
 Limit: -19 dBm/150 kHz Notes: None



Figure 8.3-116: Conducted emission 1 MHz away from the lower band edge

Frequency: 2109 MHz Mode: Single-carrier operation
 Meas. BW: 1 MHz Tech.: LTE 15 MHz with IoT
 Limit: -19 dBm/MHz Notes: None



Figure 8.3-117: Conducted emission at the upper band edge

Frequency: 2200 MHz Mode: Single-carrier operation
 Meas. BW: 1% of EBW Tech.: LTE 15 MHz with IoT
 Limit: -19 dBm/150 kHz Notes: None

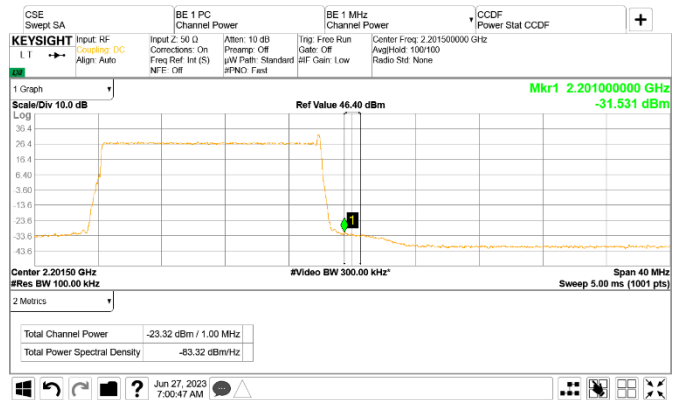


Figure 8.3-118: Conducted emission 1 MHz away from the upper band edge

Frequency: 2201 MHz Mode: Single-carrier operation
 Meas. BW: 1 MHz Tech.: LTE 15 MHz with IoT
 Limit: -19 dBm/MHz Notes: None

Test data, continued

On the plots below the measured *Channel Power* value in the “*Total Channel Power*” column must be -19 dBm and lower.



Figure 8.3-119: Conducted emission at the lower band edge

Frequency: 2110 MHz Mode: Single-carrier operation
 Meas. BW: 1% of EBW Tech.: LTE 20 MHz
 Limit: -19 dBm/200 kHz Notes: None

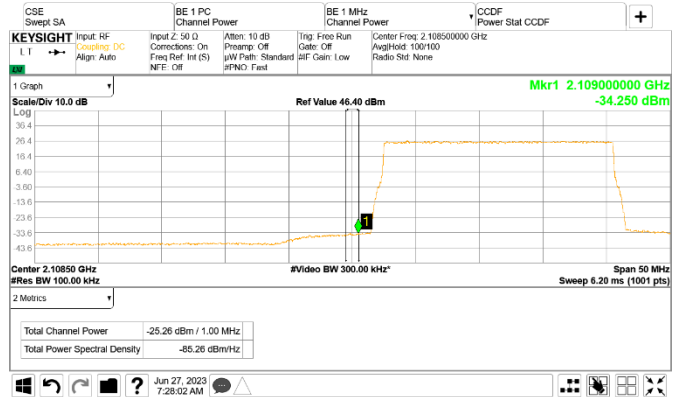


Figure 8.3-120: Conducted emission 1 MHz away from the lower band edge

Frequency: 2109 MHz Mode: Single-carrier operation
 Meas. BW: 1 MHz Tech.: LTE 20 MHz
 Limit: -19 dBm/MHz Notes: None



Figure 8.3-121: Conducted emission at the upper band edge

Frequency: 2200 MHz Mode: Single-carrier operation
 Meas. BW: 1% of EBW Tech.: LTE 20 MHz
 Limit: -19 dBm/200 kHz Notes: None

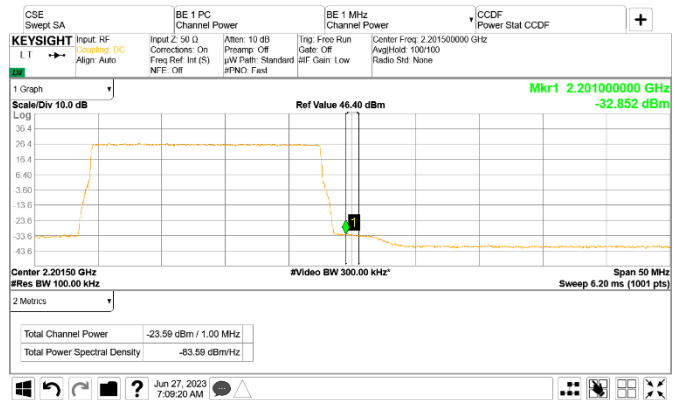


Figure 8.3-122: Conducted emission 1 MHz away from the upper band edge

Frequency: 2201 MHz Mode: Single-carrier operation
 Meas. BW: 1 MHz Tech.: LTE 20 MHz
 Limit: -19 dBm/MHz Notes: None

Test data, continued

On the plots below the measured *Channel Power* value in the “*Total Channel Power*” column must be -19 dBm and lower.



Figure 8.3-123: Conducted emission at the lower band edge

Frequency: 2110 MHz Mode: Single-carrier operation
 Meas. BW: 1% of EBW Tech.: LTE 20 MHz with IoT
 Limit: -19 dBm/200 kHz Notes: None



Figure 8.3-124: Conducted emission 1 MHz away from the lower band edge

Frequency: 2109 MHz Mode: Single-carrier operation
 Meas. BW: 1 MHz Tech.: LTE 20 MHz with IoT
 Limit: -19 dBm/MHz Notes: None



Figure 8.3-125: Conducted emission at the upper band edge

Frequency: 2200 MHz Mode: Single-carrier operation
 Meas. BW: 1% of EBW Tech.: LTE 20 MHz with IoT
 Limit: -19 dBm/200 kHz Notes: None

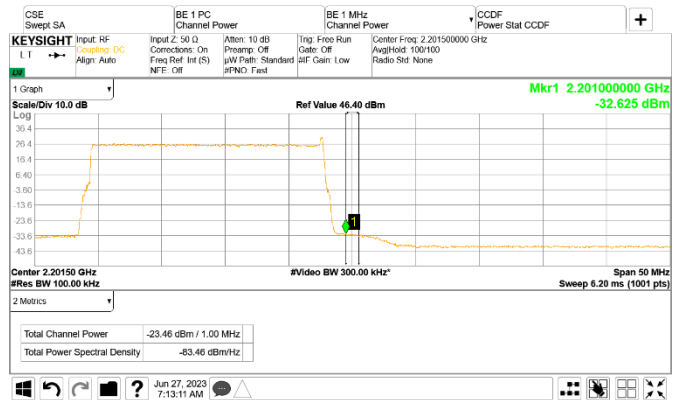


Figure 8.3-126: Conducted emission 1 MHz away from the upper band edge

Frequency: 2201 MHz Mode: Single-carrier operation
 Meas. BW: 1 MHz Tech.: LTE 20 MHz with IoT
 Limit: -19 dBm/MHz Notes: None

Test data, continued

On the plots below the measured *Channel Power* value in the “*Total Channel Power*” column must be -19 dBm and lower.



Figure 8.3-127: Conducted emission at the lower band edge

Frequency: 2110 MHz Mode: Multi-carrier operation
 Meas. BW: 1% of EBW Tech.: $2 \times$ LTE 5 MHz with IoT1
 Limit: -19 dBm/50 kHz Notes: None

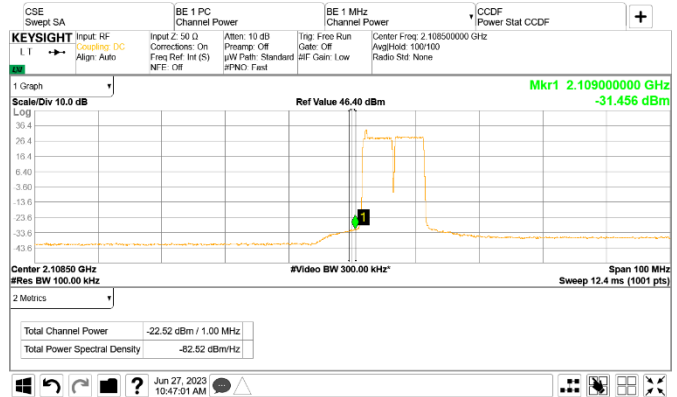


Figure 8.3-128: Conducted emission 1 MHz away from the lower band edge

Frequency: 2109 MHz Mode: Multi-carrier operation
 Meas. BW: 1 MHz Tech.: $2 \times$ LTE 5 MHz with IoT1
 Limit: -19 dBm/MHz Notes: None



Figure 8.3-129: Conducted emission at the upper band edge

Frequency: 2200 MHz Mode: Multi-carrier operation
 Meas. BW: 1% of EBW Tech.: $2 \times$ LTE 5 MHz with IoT1
 Limit: -19 dBm/50 kHz Notes: None

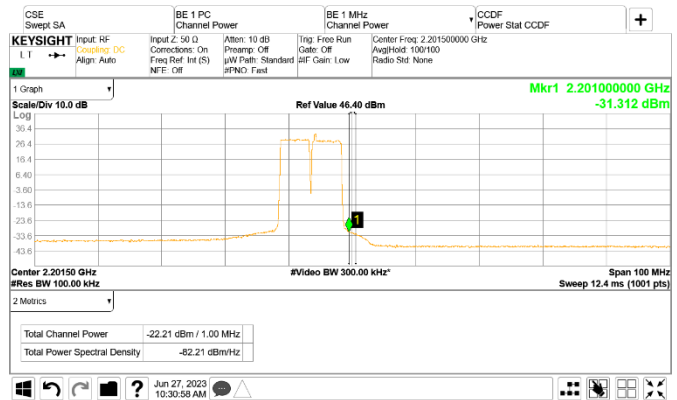


Figure 8.3-130: Conducted emission 1 MHz away from the upper band edge

Frequency: 2201 MHz Mode: Multi-carrier operation
 Meas. BW: 1 MHz Tech.: $2 \times$ LTE 5 MHz with IoT1
 Limit: -19 dBm/MHz Notes: None

Test data, continued

On the plots below the measured *Channel Power* value in the “*Total Channel Power*” column must be -19 dBm and lower.



Figure 8.3-131: Conducted emission at the lower band edge

Frequency: 2110 MHz Mode: Multi-carrier operation
 Meas. BW: 1% of EBW Tech.: $3 \times$ LTE 5 MHz with IB (IoT1)
 Limit: -19 dBm/50 kHz Notes: None

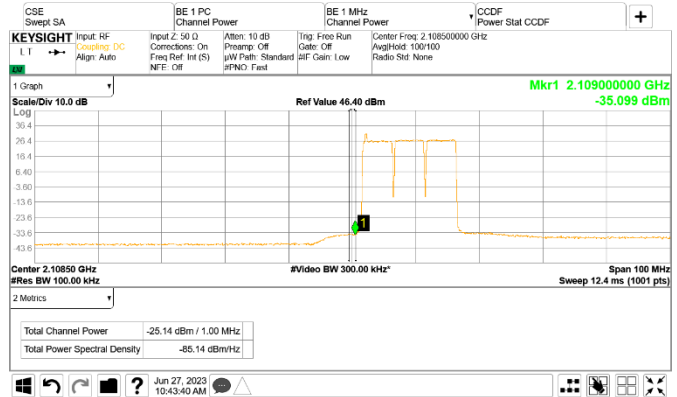


Figure 8.3-132: Conducted emission 1 MHz away from the lower band edge

Frequency: 2109 MHz Mode: Multi-carrier operation
 Meas. BW: 1 MHz Tech.: $3 \times$ LTE 5 MHz with IB (IoT1)
 Limit: -19 dBm/MHz Notes: None



Figure 8.3-133: Conducted emission at the upper band edge

Frequency: 2200 MHz Mode: Multi-carrier operation
 Meas. BW: 1% of EBW Tech.: $3 \times$ LTE 5 MHz with IB (IoT1)
 Limit: -19 dBm/50 kHz Notes: None

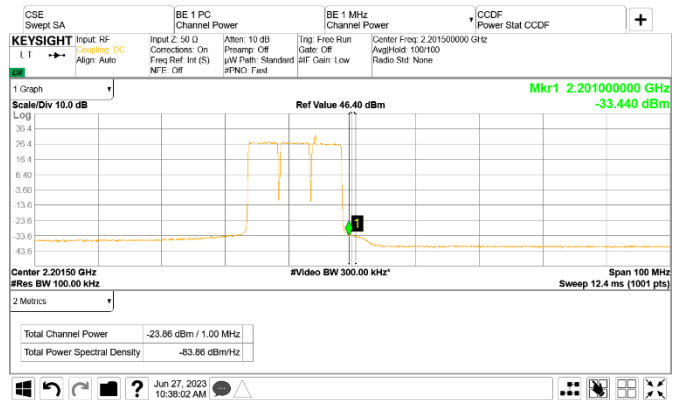


Figure 8.3-134: Conducted emission 1 MHz away from the upper band edge

Frequency: 2201 MHz Mode: Multi-carrier operation
 Meas. BW: 1 MHz Tech.: $3 \times$ LTE 5 MHz with IB (IoT1)
 Limit: -19 dBm/MHz Notes: None

Test data, continued

On the plots below the measured *Channel Power* value in the “*Total Channel Power*” column must be -19 dBm and lower.



Figure 8.3-135: Conducted emission at the lower band edge

Frequency: 2110 MHz Mode: Multi-carrier operation
 Meas. BW: 1% of EBW Tech.: $6 \times$ LTE 5 MHz with IB (IoT1)
 Limit: -19 dBm/50 kHz Notes: None

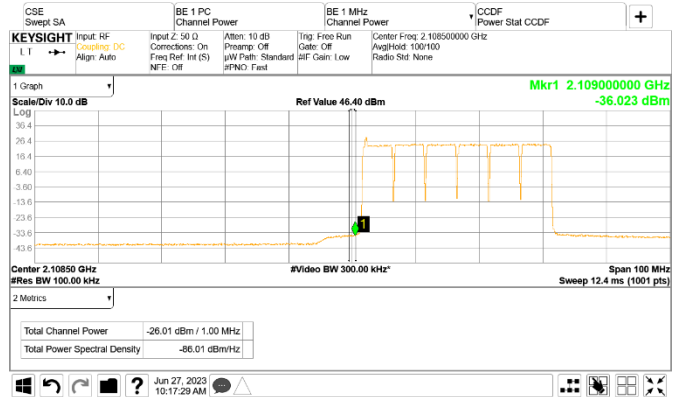


Figure 8.3-136: Conducted emission 1 MHz away from the lower band edge

Frequency: 2109 MHz Mode: Multi-carrier operation
 Meas. BW: 1 MHz Tech.: $6 \times$ LTE 5 MHz with IB (IoT1)
 Limit: -19 dBm/MHz Notes: None



Figure 8.3-137: Conducted emission at the upper band edge

Frequency: 2200 MHz Mode: Multi-carrier operation
 Meas. BW: 1% of EBW Tech.: $6 \times$ LTE 5 MHz with IB (IoT1)
 Limit: -19 dBm/50 kHz Notes: None

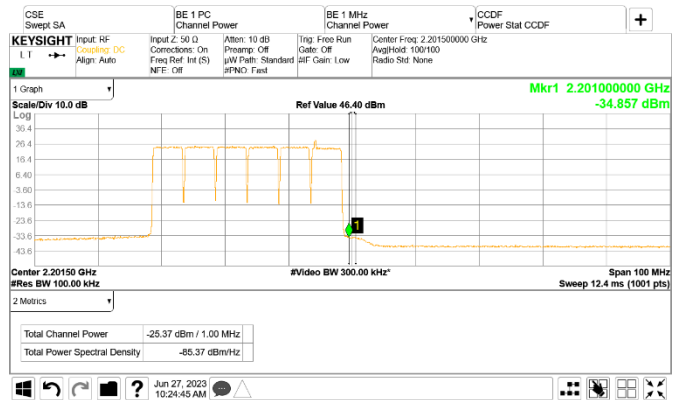


Figure 8.3-138: Conducted emission 1 MHz away from the upper band edge

Frequency: 2201 MHz Mode: Multi-carrier operation
 Meas. BW: 1 MHz Tech.: $6 \times$ LTE 5 MHz with IB (IoT1)
 Limit: -19 dBm/MHz Notes: None

Test data, continued

On the plots below the measured *Channel Power* value in the “*Total Channel Power*” column must be -19 dBm and lower.



Figure 8.3-139: Conducted emission at the lower band edge

Frequency: 2110 MHz Mode: Multi-carrier operation
 Meas. BW: 1% of EBW Tech.: $6 \times$ LTE 15 MHz with GB
 Limit: -19 dBm/150 kHz Notes: None

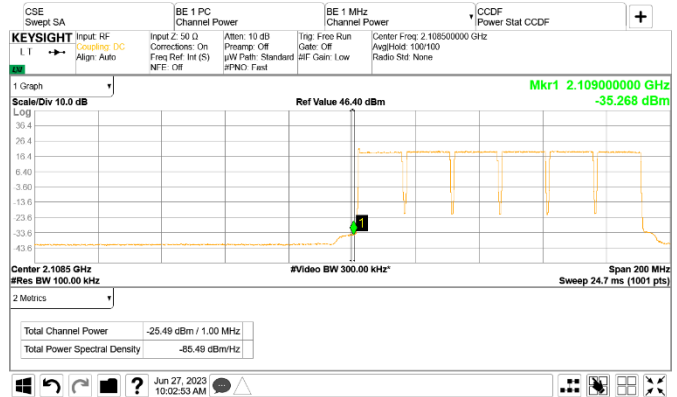


Figure 8.3-140: Conducted emission 1 MHz away from the lower band edge

Frequency: 2109 MHz Mode: Multi-carrier operation
 Meas. BW: 1 MHz Tech.: $6 \times$ LTE 15 MHz with GB
 Limit: -19 dBm/MHz Notes: None



Figure 8.3-141: Conducted emission at the upper band edge

Frequency: 2200 MHz Mode: Multi-carrier operation
 Meas. BW: 1% of EBW Tech.: $6 \times$ LTE 15 MHz with GB
 Limit: -19 dBm/150 kHz Notes: None

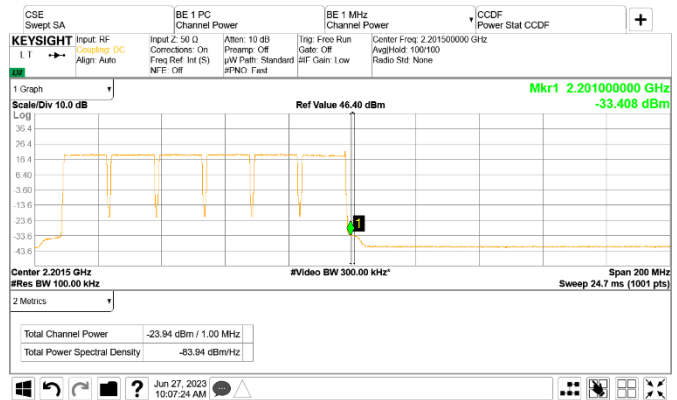


Figure 8.3-142: Conducted emission 1 MHz away from the upper band edge

Frequency: 2201 MHz Mode: Multi-carrier operation
 Meas. BW: 1 MHz Tech.: $6 \times$ LTE 15 MHz with GB
 Limit: -19 dBm/MHz Notes: None

Test data, continued

On the plots below the measured **Channel Power** value in the “**Total Channel Power**” column must be **-19 dBm** and lower.

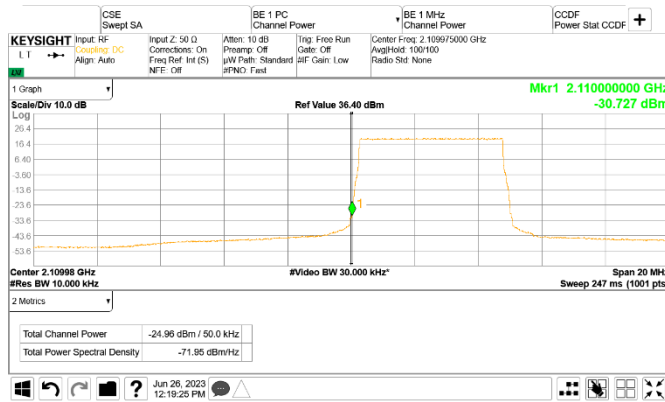


Figure 8.3-143: Conducted emission at the lower band edge

Frequency: 2110 MHz Mode: Single-carrier operation
 Meas. BW: 1% of EBW Tech.: NR 5 MHz
 Limit: -19 dBm/50 kHz Notes: None

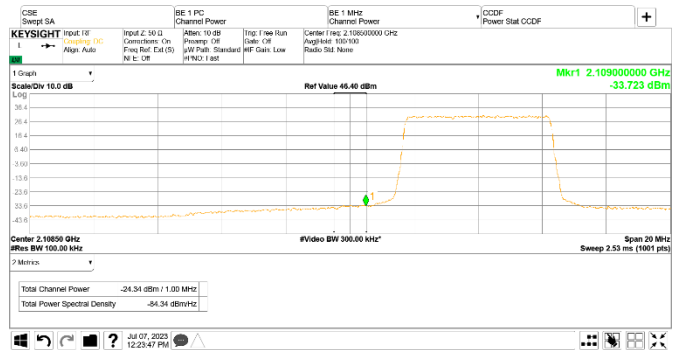


Figure 8.3-144: Conducted emission 1 MHz away from the lower band edge

Frequency: 2109 MHz Mode: Single-carrier operation
 Meas. BW: 1 MHz Tech.: NR 5 MHz
 Limit: -19 dBm/MHz Notes: None

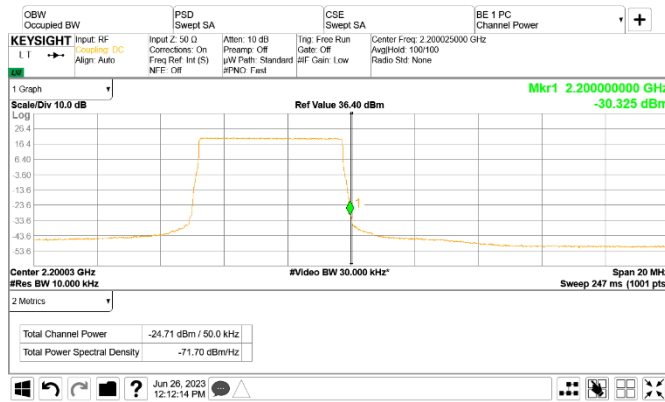


Figure 8.3-145: Conducted emission at the upper band edge

Frequency: 2200 MHz Mode: Single-carrier operation
 Meas. BW: 1% of EBW Tech.: NR 5 MHz
 Limit: -19 dBm/50 kHz Notes: None

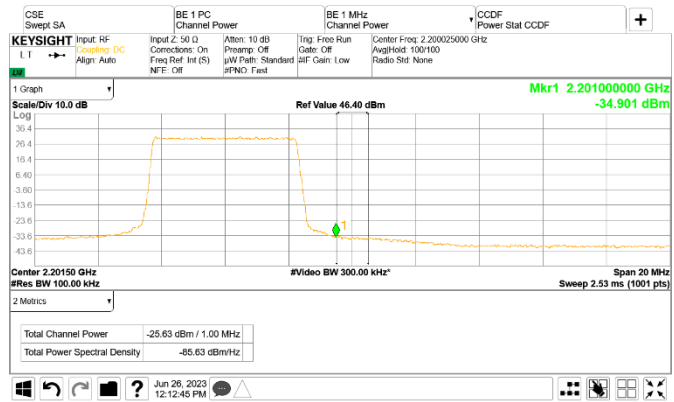


Figure 8.3-146: Conducted emission 1 MHz away from the upper band edge

Frequency: 2201 MHz Mode: Single-carrier operation
 Meas. BW: 1 MHz Tech.: NR 5 MHz
 Limit: -19 dBm/MHz Notes: None

Test data, continued

On the plots below the measured *Channel Power* value in the “*Total Channel Power*” column must be -19 dBm and lower.

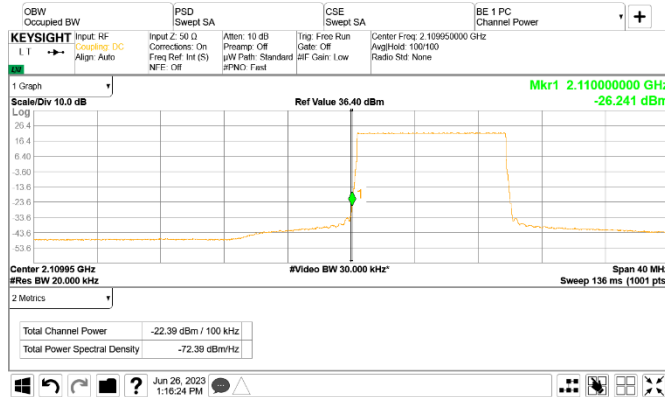


Figure 8.3-147: Conducted emission at the lower band edge

Frequency: 2110 MHz Mode: Single-carrier operation
 Meas. BW: 1% of EBW Tech.: NR 10 MHz
 Limit: -19 dBm/100 kHz Notes: None

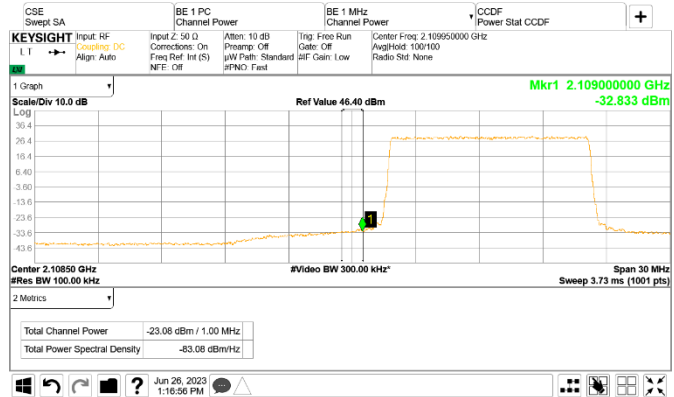


Figure 8.3-148: Conducted emission 1 MHz away from the lower band edge

Frequency: 2109 MHz Mode: Single-carrier operation
 Meas. BW: 1 MHz Tech.: NR 10 MHz
 Limit: -19 dBm/MHz Notes: None



Figure 8.3-149: Conducted emission at the upper band edge

Frequency: 2200 MHz Mode: Single-carrier operation
 Meas. BW: 1% of EBW Tech.: NR 10 MHz
 Limit: -19 dBm/100 kHz Notes: None



Figure 8.3-150: Conducted emission 1 MHz away from the upper band edge

Frequency: 2201 MHz Mode: Single-carrier operation
 Meas. BW: 1 MHz Tech.: NR 10 MHz
 Limit: -19 dBm/MHz Notes: None

Test data, continued

On the plots below the measured *Channel Power* value in the “*Total Channel Power*” column must be -19 dBm and lower.



Figure 8.3-151: Conducted emission at the lower band edge

Frequency: 2110 MHz Mode: Single-carrier operation
 Meas. BW: 1% of EBW Tech.: NR 15 MHz
 Limit: -19 dBm/150 kHz Notes: None



Figure 8.3-152: Conducted emission 1 MHz away from the lower band edge

Frequency: 2109 MHz Mode: Single-carrier operation
 Meas. BW: 1 MHz Tech.: NR 15 MHz
 Limit: -19 dBm/MHz Notes: None



Figure 8.3-153: Conducted emission at the upper band edge

Frequency: 2200 MHz Mode: Single-carrier operation
 Meas. BW: 1% of EBW Tech.: NR 15 MHz
 Limit: -19 dBm/150 kHz Notes: None

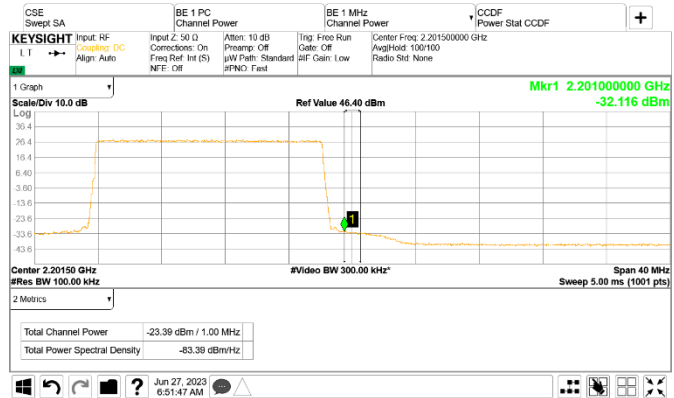


Figure 8.3-154: Conducted emission 1 MHz away from the upper band edge

Frequency: 2201 MHz Mode: Single-carrier operation
 Meas. BW: 1 MHz Tech.: NR 15 MHz
 Limit: -19 dBm/MHz Notes: None

Test data, continued

On the plots below the measured *Channel Power* value in the “*Total Channel Power*” column must be -19 dBm and lower.



Figure 8.3-155: Conducted emission at the lower band edge

Frequency: 2110 MHz Mode: Single-carrier operation
 Meas. BW: 1% of EBW Tech.: NR 20 MHz
 Limit: -19 dBm/200 kHz Notes: None

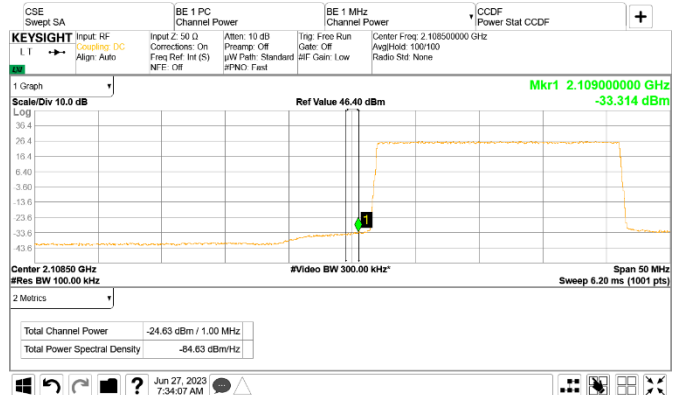


Figure 8.3-156: Conducted emission 1 MHz away from the lower band edge

Frequency: 2109 MHz Mode: Single-carrier operation
 Meas. BW: 1 MHz Tech.: NR 20 MHz
 Limit: -19 dBm/MHz Notes: None

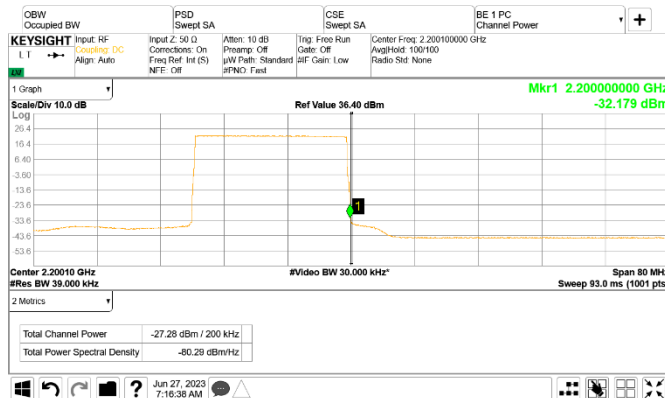


Figure 8.3-157: Conducted emission at the upper band edge

Frequency: 2200 MHz Mode: Single-carrier operation
 Meas. BW: 1% of EBW Tech.: NR 20 MHz
 Limit: -19 dBm/200 kHz Notes: None

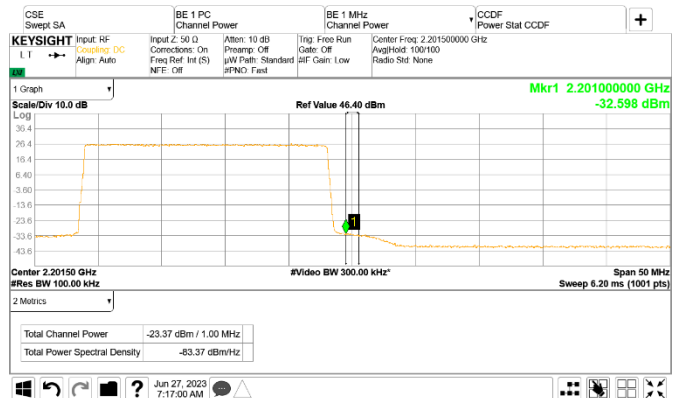


Figure 8.3-158: Conducted emission 1 MHz away from the upper band edge

Frequency: 2201 MHz Mode: Single-carrier operation
 Meas. BW: 1 MHz Tech.: NR 20 MHz
 Limit: -19 dBm/MHz Notes: None

Test data, continued

On the plots below the measured *Channel Power* value in the “*Total Channel Power*” column must be -19 dBm and lower.



Figure 8.3-159: Conducted emission at the lower band edge

Frequency: 2110 MHz Mode: Single-carrier operation
 Meas. BW: 1% of EBW Tech.: NR 25 MHz
 Limit: -19 dBm/250 kHz Notes: None



Figure 8.3-160: Conducted emission 1 MHz away from the lower band edge

Frequency: 2109 MHz Mode: Single-carrier operation
 Meas. BW: 1 MHz Tech.: NR 25 MHz
 Limit: -19 dBm/MHz Notes: None



Figure 8.3-161: Conducted emission at the upper band edge

Frequency: 2200 MHz Mode: Single-carrier operation
 Meas. BW: 1% of EBW Tech.: NR 25 MHz
 Limit: -19 dBm/250 kHz Notes: None

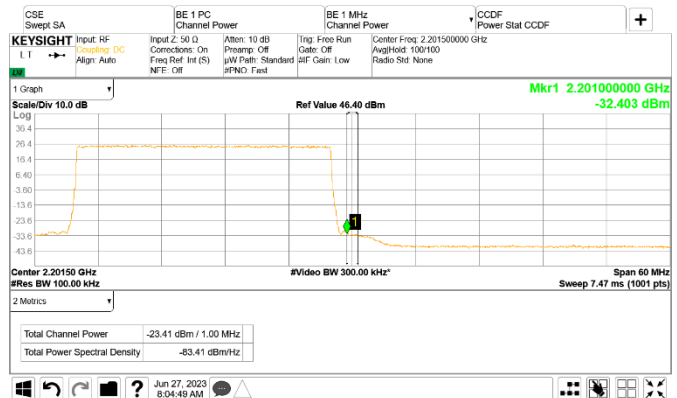


Figure 8.3-162: Conducted emission 1 MHz away from the upper band edge

Frequency: 2201 MHz Mode: Single-carrier operation
 Meas. BW: 1 MHz Tech.: NR 25 MHz
 Limit: -19 dBm/MHz Notes: None

Test data, continued

On the plots below the measured *Channel Power* value in the “*Total Channel Power*” column must be -19 dBm and lower.



Figure 8.3-163: Conducted emission at the lower band edge

Frequency: 2110 MHz Mode: Single-carrier operation
 Meas. BW: 1% of EBW Tech.: NR 30 MHz
 Limit: -19 dBm/300 kHz Notes: None



Figure 8.3-164: Conducted emission 1 MHz away from the lower band edge

Frequency: 2109 MHz Mode: Single-carrier operation
 Meas. BW: 1 MHz Tech.: NR 30 MHz
 Limit: -19 dBm/MHz Notes: None



Figure 8.3-165: Conducted emission at the upper band edge

Frequency: 2200 MHz Mode: Single-carrier operation
 Meas. BW: 1% of EBW Tech.: NR 30 MHz
 Limit: -19 dBm/300 kHz Notes: None

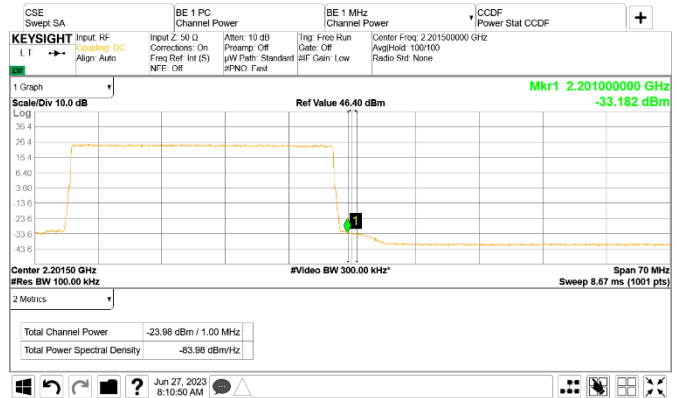


Figure 8.3-166: Conducted emission 1 MHz away from the upper band edge

Frequency: 2201 MHz Mode: Single-carrier operation
 Meas. BW: 1 MHz Tech.: NR 30 MHz
 Limit: -19 dBm/MHz Notes: None

Test data, continued

On the plots below the measured *Channel Power* value in the “*Total Channel Power*” column must be -19 dBm and lower.



Figure 8.3-167: Conducted emission at the lower band edge

Frequency: 2110 MHz Mode: Single-carrier operation
 Meas. BW: 1% of EBW Tech.: NR 40 MHz
 Limit: -19 dBm/400 kHz Notes: None



Figure 8.3-168: Conducted emission 1 MHz away from the lower band edge

Frequency: 2109 MHz Mode: Single-carrier operation
 Meas. BW: 1 MHz Tech.: NR 40 MHz
 Limit: -19 dBm/MHz Notes: None



Figure 8.3-169: Conducted emission at the upper band edge

Frequency: 2200 MHz Mode: Single-carrier operation
 Meas. BW: 1% of EBW Tech.: NR 40 MHz
 Limit: -19 dBm/400 kHz Notes: None

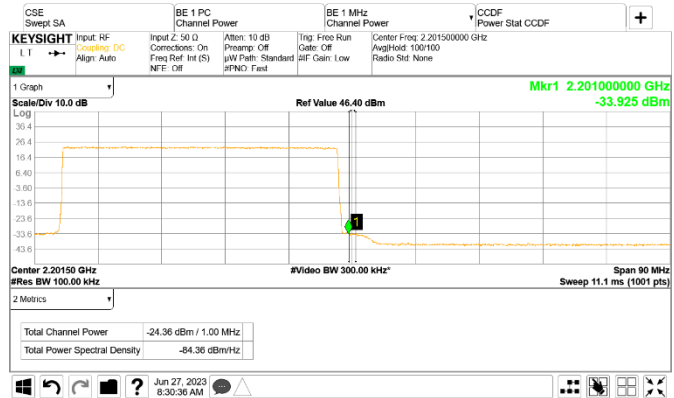


Figure 8.3-170: Conducted emission 1 MHz away from the upper band edge

Frequency: 2201 MHz Mode: Single-carrier operation
 Meas. BW: 1 MHz Tech.: NR 40 MHz
 Limit: -19 dBm/MHz Notes: None

Test data, continued

On the plots below the measured *Channel Power* value in the “*Total Channel Power*” column must be -19 dBm and lower.



Figure 8.3-171: Conducted emission at the lower band edge

Frequency: 2110 MHz Mode: Multi-carrier operation
 Meas. BW: 1% of EBW Tech.: $2 \times NR$ 5 MHz
 Limit: -19 dBm/50 kHz Notes: None

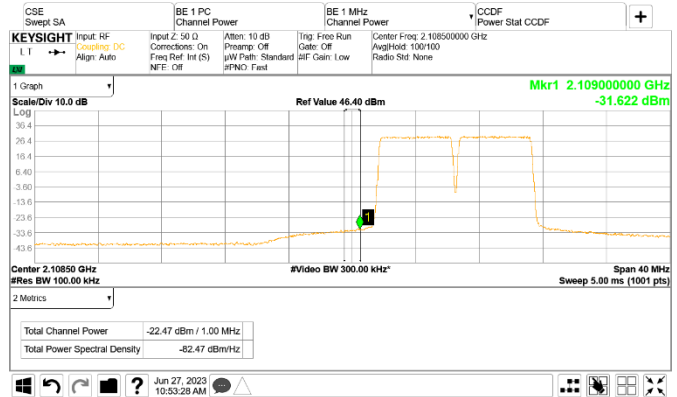


Figure 8.3-172: Conducted emission 1 MHz away from the lower band edge

Frequency: 2109 MHz Mode: Multi-carrier operation
 Meas. BW: 1 MHz Tech.: $2 \times NR$ 5 MHz
 Limit: -19 dBm/MHz Notes: None



Figure 8.3-173: Conducted emission at the upper band edge

Frequency: 2200 MHz Mode: Multi-carrier operation
 Meas. BW: 1% of EBW Tech.: $2 \times NR$ 5 MHz
 Limit: -19 dBm/50 kHz Notes: None

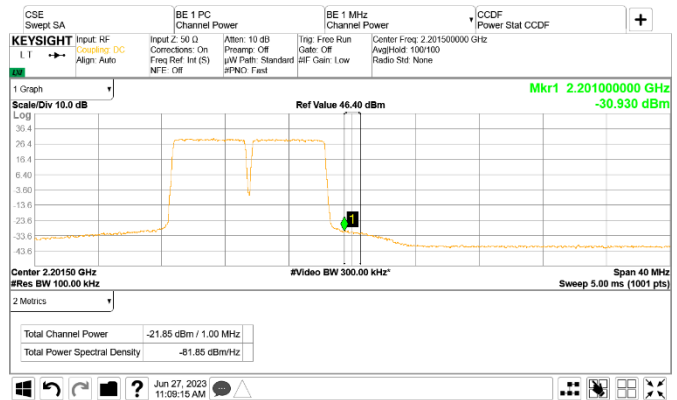


Figure 8.3-174: Conducted emission 1 MHz away from the upper band edge

Frequency: 2201 MHz Mode: Multi-carrier operation
 Meas. BW: 1 MHz Tech.: $2 \times NR$ 5 MHz
 Limit: -19 dBm/MHz Notes: None